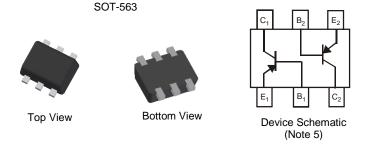


Features

- Epitaxial Die Construction
- Complementary PNP Type Available (BC847BV)
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208
- Weight: 0.003 grams (Approximate)



Ordering Information (Note 4)

-		
Part Number	Case	Packaging
BC857BV-7	SOT-563	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

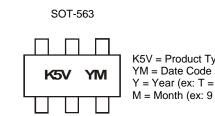
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

5. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways).

Marking Information



K5V = Product Type Marking Code YM = Date Code Marking Y = Year (ex: T = 2006) M = Month (ex: 9 = September)

Balo Codo Hoj													
Year	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
Code	Р	R	S	Т	U	V	W	Х	Y	Z	А	В	С
Month	Jan	Feb	Mar	Apr	Ma	y J	un	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5		6	7	8	9	0	Ν	D



Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-45	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current	Ic	-100	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	150	mW
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	833	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

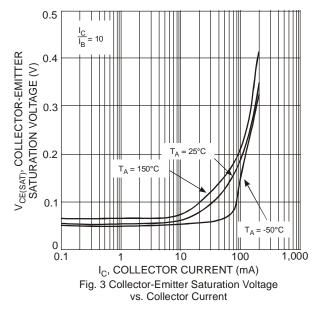
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage (Note 7)	V _{(BR)CBO}	-50	_	_	V	$I_{\rm C} = 10 \mu A, I_{\rm B} = 0$
Collector-Emitter Breakdown Voltage (Note 7)	V _{(BR)CEO}	-45	_	_	V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage (Note 7)	V _{(BR)EBO}	-5	_	_	V	$I_{E} = 1\mu A, I_{C} = 0$
DC Current Gain (Note 7)	h _{FE}	220	290	475	—	V _{CE} = -5.0V, I _C = -2.0mA
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(SAT)}			-100 -400	mV	I _C = -10mA, I _B = -0.5mA I _C = -100mA, I _B = -5.0mA
Base-Emitter Saturation Voltage (Note 7)	V _{BE(SAT)}		-700 -900		mV	$I_{C} = -10mA$, $I_{B} = -0.5mA$ $I_{C} = -100mA$, $I_{B} = -5.0mA$
Base-Emitter Voltage (Note 7)	V _{BE(ON)}	-600		-750 -820	mV	$V_{CE} = -5.0V$, $I_C = -2.0mA$ $V_{CE} = -5.0V$, $I_C = -10mA$
Collector Cut-Off Current (Note 7)	les e	_	_	-15	nA	$V_{CB} = -30V$
	ICBO	_		-4.0	μA	V _{CB} = -30V, T _A = +150°C
Gain Bandwidth Product	f _T	100		_	MHz	$V_{CE} = -5.0V, I_{C} = -10mA, f = 100MHz$
Output Capacitance	COB	_		4.5	pF	V _{CB} = -10V, f = 1.0MHz
Noise Figure	NF		_	10	dB	$\label{eq:lc} \begin{array}{l} I_C = -0.2 m A, \ V_{CE} = -5.0 V dc, \\ R_S = 2.0 K \Omega, \ f = 1.0 K Hz, \ BW = 200 Hz \end{array}$

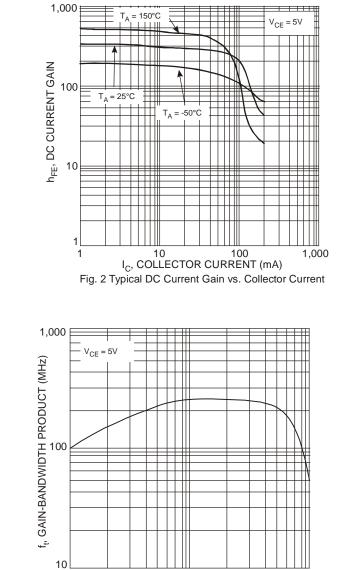
 Device mounted on FR-4 PCB, 1-inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
Short duration pulse test used to minimize self-heating effect. Notes:



250 (M) 200 150 a^{0} 50 b^{0} b^{0}







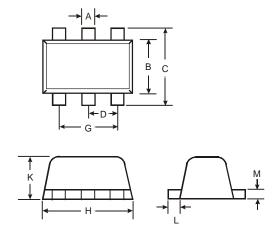
1 10 100 I_C, COLLECTOR CURRENT (mA) Fig. 4 Typical Gain-Bandwidth Product vs. Collector Current

BC857BV



Package Outline Dimensions

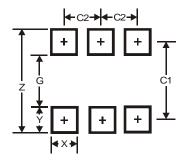
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT-563						
Dim	Min	Max	Тур				
Α	0.15	0.30	0.20				
В	1.10	1.25	1.20				
С	1.55	1.70	1.60				
D	-	-	0.50				
G	0.90	1.10	1.00				
Н	1.50	1.70	1.60				
к	0.55	0.60	0.60				
L	0.10	0.30	0.20				
Μ	0.10	0.18	0.11				
All	All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5



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